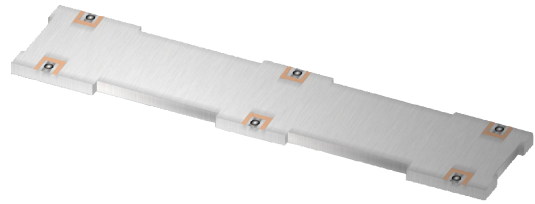


- 2.04 - 2.24 GHz
- LOW LOSS
- LOW VSWR
- HIGH ISOLATION
- SURFACE MOUNT



TECHNICAL DESCRIPTION / APPLICATION

MULTI-MIX[®] F SERIES IN-LINE COUPLERS

The Multi-Mix[®] ILC-F series provides a power divider and combiner function with low insertion loss, high isolation, and high power handling in a small outline. The ILC series are composed of serial connected multi-couplers with each coupler having a different nominal coupling value. Equal split loss is maintained at all of the coupled ports, since the direct-path loss of previous couplers is added. Each of the paths through a divider / combiner pair have equal insertion phase, but the individual port paths do not. Accurate phase and amplitude balance make them ideal for applications involving power amplifiers, signal distribution and processing.

ILC-F in-line couplers are fusion bonded multilayer stripline assemblies. The fusion bonding process yields a homogeneous monolithic dielectric structure with reliability, ruggedness, and electrical performance that is superior to conventional adhesive bonding techniques.

The ILC-F series is an easy to install SMD designed specifically for the full spectrum of wireless applications. The high stability ceramic filled PTFE dielectrics utilized in these components are compatible with common substrates such as FR-4, G-10, and polyamide. The wrap around ground plane provides excellent EM shielding.

Additional benefits include:

- Cost effective for commercial wireless applications
- Operating temperature range -55°C to $+85^{\circ}\text{C}$.
- Can be integrated with other Multi-Mix[®] components in a multi-function



AVAILABLE ON
TAPE & REEL

RELIABILITY

The product family has passed environmental screening including Thermal shock, Burn-in, Acceleration, Vibration, Mechanical Shock, Moisture Resistance, Resistance to Solder Heat, and Thermal Cycling Life Test (>1000 cycles).

THE MULTI-MIX[®] PROCESS

Multi-Mix[®] is a manufacturing process based on fluoropolymer composite substrates that are fusion bonded together into a multilayer structure. The fusion bonding process yields a homogeneous monolithic structure with superior performance at microwave and millimeter wave frequencies. The bonded layers can contain embedded semiconductors, MMICs, etched resistors, circuit patterns, and plated-through vias to form a SMD module that requires no additional packaging and is suitable for automated assembly.

THE MULTI-MIX MICROTECHNOLOGY[®] GROUP IS ISO-9001 REGISTERED



U.S. patent 6,099,677 and other patents pending.

ELECTRICAL

FREQUENCY RANGE	2.04 TO 2.24 GHz
NORMAL COUPLING	4.8 dB
INSERTION LOSS	0.25 dB (TYP), 0.35 dB (MAX)
VSWR	1.25:1 (MAX)
AMPLITUDE BALANCE	+/- 0.5 dB (TYP), ±0.5 dB (MAX)
ISOLATION	22 dB (MIN)
MAXIMUM INPUT POWER	100W (MAX)

MECHANICAL

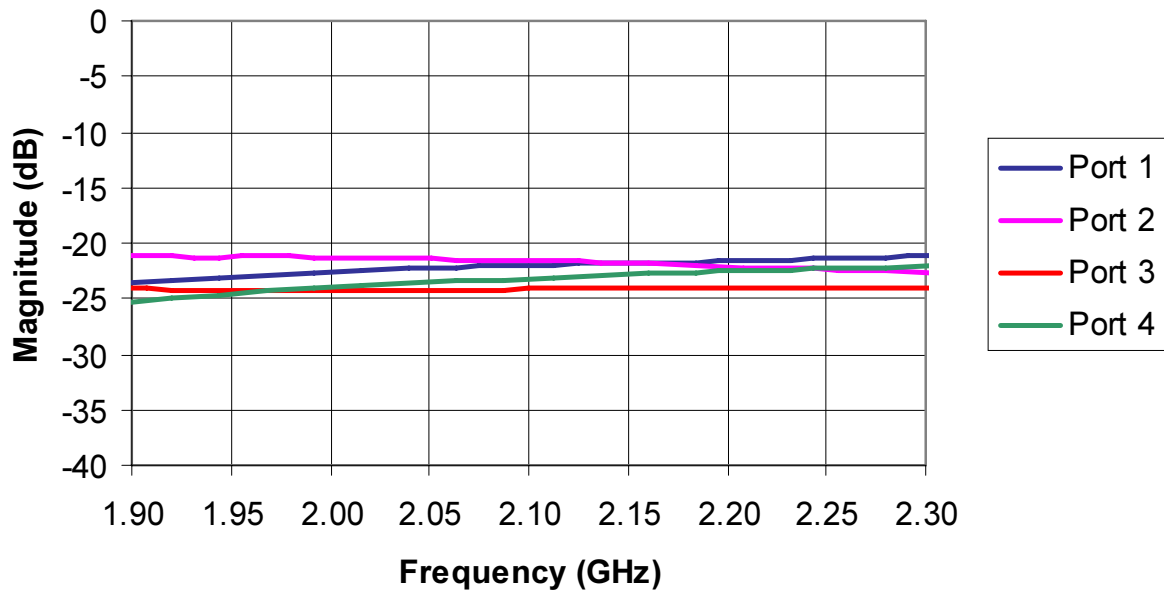
SIZE / OUTLINE	5.48 X 0.40 X 0.07 inches
WEIGHT	0.21 oz. (5.75 g)
RF INTERFACE	Surface Mount

ENVIRONMENTAL

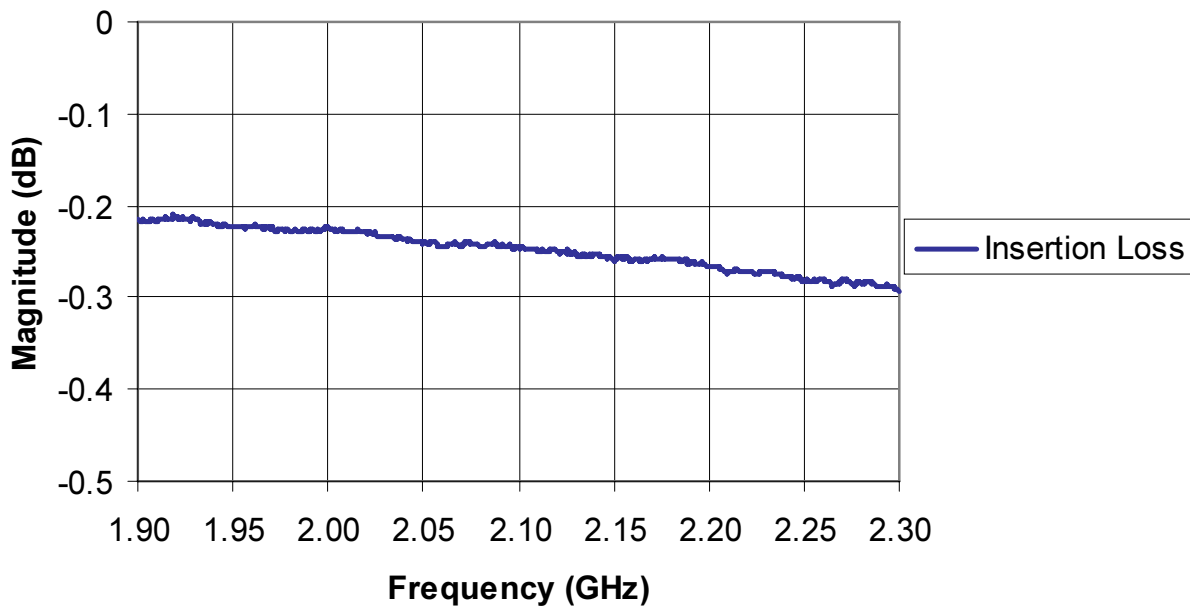
OPERATING TEMPERATURE RANGE	-55° To + 85° C
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Return Loss

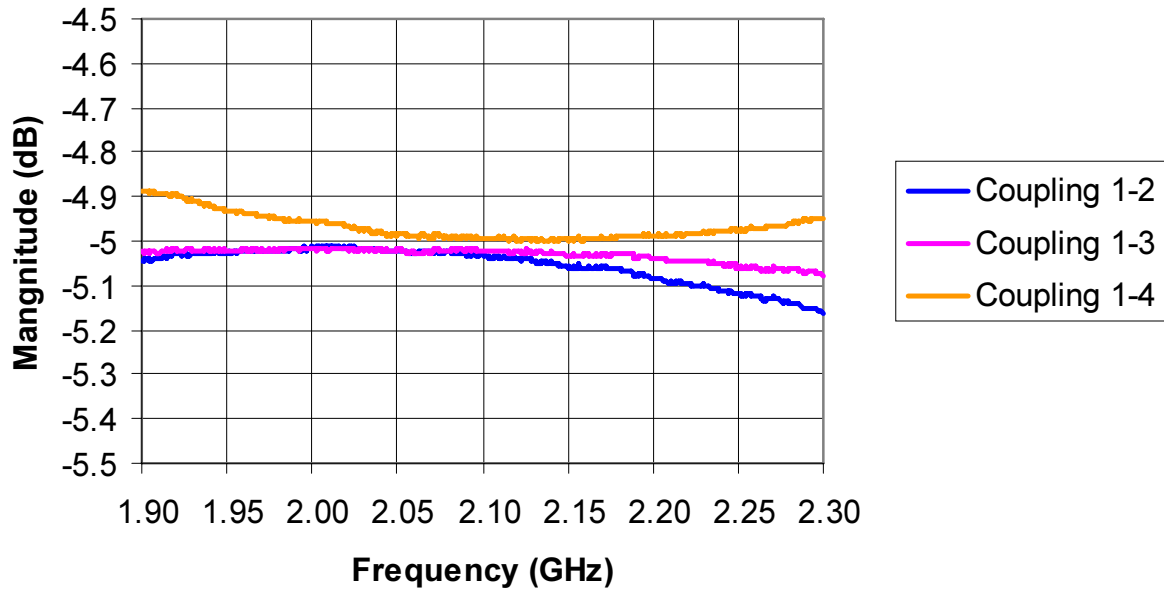


Insertion Loss

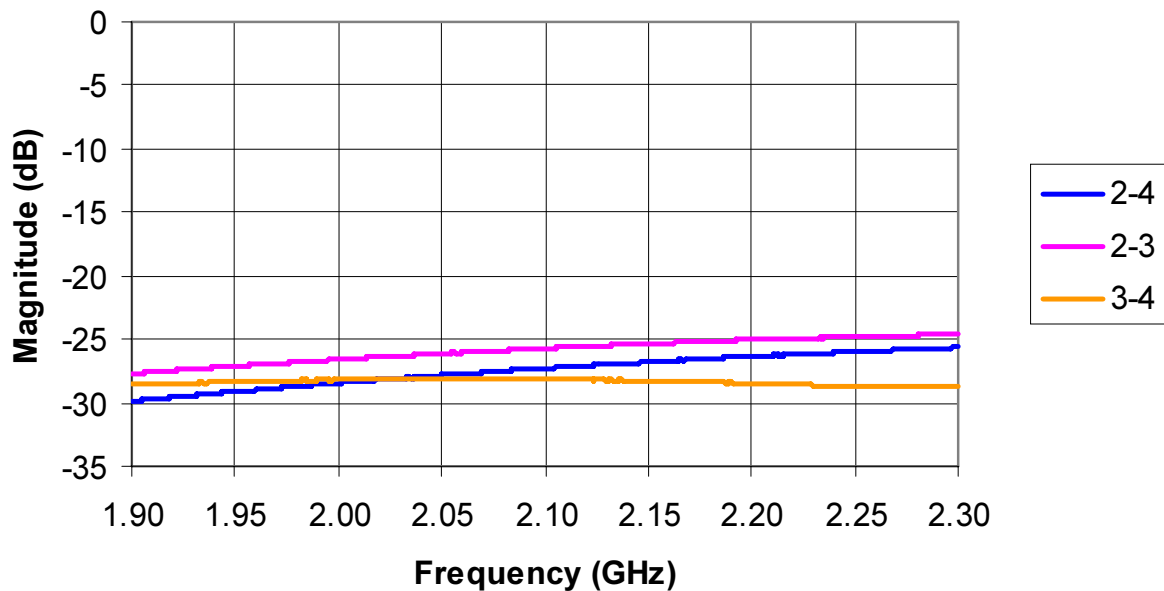


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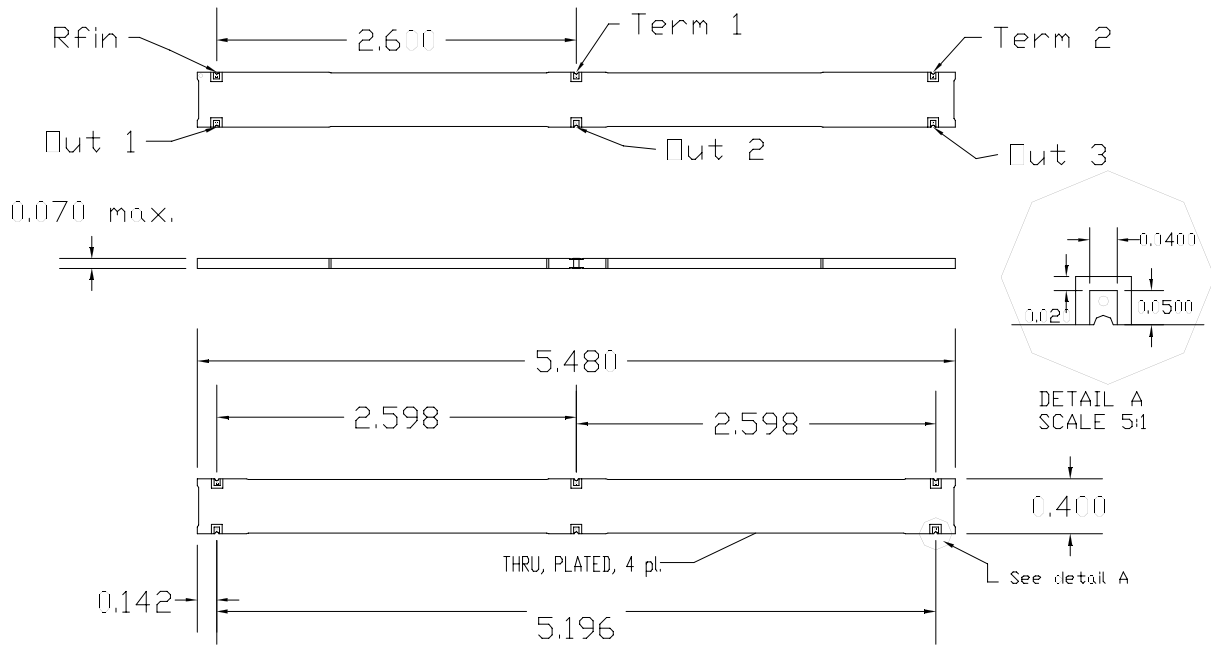
Coupling



Isolation



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- NOTES:
1. ALL DIMENSIONS ARE IN INCHES.
 2. TOLERANCES: -3 PLACE DECIMALS; ±.005.

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